

One out of two analog switch circuit

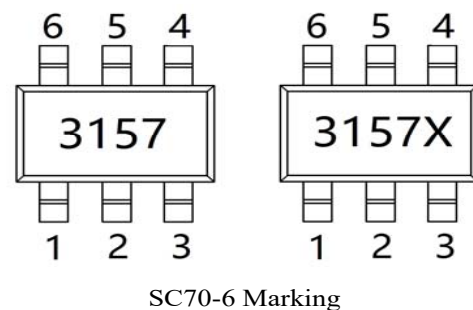
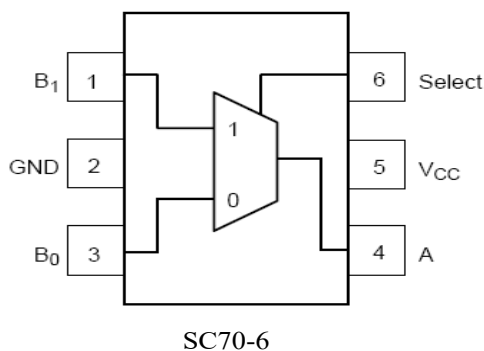
summary

ET3157 is an analog switch based on CMOS technology. It has low power consumption, low transmission delay and low output impedance. The voltage output range of analog signal and digital signal can be from V_{CC} or GND. The select input terminal has over-voltage protection, which allows the input voltage to be higher than V_{CC} , up to 7V, and the pin will not be burned.

Functional features

- low power consumption
- High transmission speed
- Flip standard CMOS logic level
- High bandwidth, high linearity
- Switch for NTSC / PAL video, audio, SPDIF and HDTV
- It can be used for clock switch and data selection switch
- Low output impedance
- First break and then open protection to prevent short circuit
- Working temperature - 55 °C ~ + 125 °C
- Package form SC70-6 (3157)

Pin layout



Pin description

Pin	I/O	function
A, B ₀ , B ₁	I/O	Data port
Select	I	Control selection
V _{CC}	—	Power supply terminal
GND	—	land

Function description

Select input	function
L	B ₀ to A
H	B ₁ to A

Thermal resistance data

parameter	Symbol	numerical value	Unit
thermal resistance	θ_{JA}	270	°C/W

Limit parameter

parameter	Symbol	Range	Unit
supply voltage	V _{CC}	-0.5 ~ +7.0	V
Switching voltage (Note 1)	V _S	-0.5 ~ V _{CC} +0.5	V
Input voltage (Note 1)	V _{IN}	-0.5 ~ +7.0	V
Vin @ 0V input current clamp diode	I _{IK}	-50	mA
Output current	I _{OUT}	128	mA
Power to ground current	I _{CC} /I _{GND}	100	mA
Storage temperature range	T _{stg}	-65 ~ +150	°C
Maximum junction temperature	T _J	150	°C
Wire temperature (welding, 10 seconds)	T _L	260	°C
Total power consumption (85°C)	P _D	180	mW

Exceeding the maximum value of DC limit parameters may cause irreparable damage to the circuit. If there is no special case, ensure that the power supply voltage, operating temperature and load characteristics of input / output of the whole working system are within the above range.

Note 1: the negative voltage of I / O can be exceeded according to the clamping diode current range of input / output.

Working environment (Note 2)

parameter	Symbol	MID	MXA	Unit
supply voltage	V _{CC}	1.65	5.5	V
Select terminal input voltage	V _{IN}	0	V _{CC}	V
Switch input voltage	V _{IN}	0	V _{CC}	V
Output voltage	V _{OUT}	0	V _{CC}	V
Working temperature	T _A	-55	+125	°C
Enter the rising and falling time. Input voltage V _{CC} = 2.3V ~ 3.6V. Input voltage V _{CC} = 4.5V ~ 5.5V.	t _r , t _f	0 0	10 5.0	ns/V

Note: The input voltage of 2: Select terminal must be set to a high level or a low level, and cannot be left floating.

Electrical parameter

Parameter	Sign	Test Condition	V _{CC}	T _A =25℃			T _A =-40℃~+85℃		Unit
				Min	Typ	Max	Min	Max	
DC characteristic									
V _{IH}	High level input		1.65-1.95				0.75V _{CC}		V
			2.3-2.8				1.5		
			3-4.2				2.4		
			4.5-5.5				0.6V _{CC}		
V _{IL}	Input low level		1.65-1.95					0.25V _{CC}	V
			2.3-2.8					0.4	
			3-5.5					0.3V _{CC}	
I _{IN}	Leakage current input	0< V _{IN} <5.5V	0-5.5		± 0.05	± 0.1		± 1	uA
I _{OFF}	Closed state leakage electric current	0<A,B< V _{CC}	1.65-5.5		± 0.05	± 0.1		± 1	uA
I _{CC}	Quiescent current	V _{IN} =V _{CC} or GND I _{OUT} =0	5.5			1.0		10	uA
	Analog level input Into the scope		V _{CC}	0		V _{CC}	0	V _{CC}	V
R _{ON}	Switch on resistance (Note 3)	V _{IN} =0V, I _O =30mA	4.5		3.0			7.0	Ω
		V _{IN} =2.4V, I _O =-30mA			5.0			12	Ω
		V _{IN} =4.5V, I _O =-30mA			7.0			15	Ω
		V _{IN} =0V, I _O =24mA	3.0		4.0			9.0	Ω
		V _{IN} =3V , I _O =-24mA			10			20	Ω
		V _{IN} =0V, I _O =8mA	2.3		5.0			12	Ω
		V _{IN} =2.3V, I _O =-8mA			13			30	Ω
		V _{IN} =0V, I _O =4mA	1.65		6.5			20	Ω
		V _{IN} =1.65V, I _O =-4mA			17			50	Ω
R _{RANGE}	Full signal range on resistance (Note 3) (Note 7)	I _A =-30mA 0≤ V _{BI} ≤ V _{CC}	4.5					25	Ω
		I _A =-24mA 0≤ V _{BI} ≤ V _{CC}	3					50	Ω
		I _A =-8mA 0≤ V _{BI} ≤ V _{CC}	2.3					100	Ω
		I _A =-4mA 0≤ V _{BI} ≤ V _{CC}	1.65					300	Ω

ΔR_{ON}	On resistance matching between channels (Note 3) (Note 4) (Note 5)	I_A =-30mA V_{Bn} = 3.15	4.5		0.15				Ω
		I_A =-24mA V_{Bn} = 2.1	3		0.2				Ω
		I_A =-8mA V_{Bn} = 1.6	2.3		0.5				Ω
		I_A =-4mA V_{Bn} = 1.15	1.65		0.5				Ω
R_{FLAT}	On-resistance flatness (Note 3) (Note 4) (Note 6)	I_A =-30mA $0\leq V_{Bn}\leq V_{CC}$	5		6.0				Ω
		I_A =-24mA $0\leq V_{Bn}\leq V_{CC}$	3.3		12				Ω
		I_A =-8mA $0\leq V_{Bn}\leq V_{CC}$	2.5		28				Ω
		I_A =-4mA $0\leq V_{Bn}\leq V_{CC}$	1.8		125				Ω
AC characteristics									
t_{PHL} t_{PLH}	Transmission Delay (Note8)	Fig. 1 V_I =OPEN	1.65-1.95						nS
			2.3-2.7					1.2	nS
			3.0-3.5					0.8	nS
			4.5-5.5					0.3	nS
t_{PZL} t_{PZH}	Open time (a to Bn)	Fig. 1 $v_I = 2 \cdot V_{CC}$ for t_{PZL} , $v_I = 0v$ for t_{PZH}	1.65-1.95			23	7.0	24	nS
			2.3-2.7			13	3.5	14	nS
			3.0-3.5			6.9	2.5	7.6	nS
			4.5-5.5			5.2	1.7	5.7	nS
t_{PLZ} t_{PHZ}	turn - off time (port a to port b)	Fig. 1 $v_I = 2 \cdot V_{CC}$ for t_{PLZ} , $v_I = 0v$ for t_{PHZ}	1.65-1.95			12.5	3.0	13	nS
			2.3-2.7			7.0	2.0	7.5	nS
			3.0-3.5			5.0	1.5	5.3	nS
			4.5-5.5			3.5	0.8	3.8	nS
t_{B-M}	Break before connect time (Note 7)	Fig. 2, $C_L = 50pF$, $R_L = 600\Omega$	1.65-1.95				0.5		nS
			2.3-2.7				0.5		nS
			3.0-3.5				0.5		nS
			4.5-5.5				0.5		nS
Q	Charge injection (Note 7)	Fig. 3, $C_L = 0.1nF$, $V_{GEN}= 0V$ $R_{GEN}=0\Omega$	5.0		7.0				pC
			3.3		3.0				pC
OIRR	Close (note 9) Release	Fig. 4, $R_L = 50\Omega$, $f = 10MHz$	1.65-5.5		-57				dB
Xtalk	cross talk	Fig. 5, $R_L= 50\Omega$, $f =$	1.65-5.5		-54				dB

		10MHz							
BW	- 3dB bandwidth	Fig. 8, $R_L = 50 \Omega$	1.65-5.5		350M				Hz
THD	total harmonic distortion (Note 7)	$R_L=600\Omega$, $0.5V_{P-P}$ $f=600\text{Hz}—20\text{kHz}$	5.0		0.011				%
C_{IN}	Input terminal capacitance (Note 10)		0		2.3				pF
C_{IOB}	B disconnection capacitance when the port is turned off (Note 10)	Figure 6	5.0		5.0				pF
C_{IOAON}	A conduction capacitance when the port is open (Note 10)	Figure 7	5.0		15.5				pF

Note3: It is obtained by measuring the ratio of the voltage difference between the two ports A and B to the current flowing through the two ports. On-resistance is determined by the lower voltage port of port A and B

Note4: The load characteristics introduced by encapsulation are not included.

Note5: $\Delta RON = RON_{max} - RON_{min}$ in the given VCC, temperature and level range.

Note6: On-resistance flatness refers to the difference between the maximum value and the minimum value of on-resistance under specified conditions.

Note 7: Design simulation value.

Note 8: This parameter is the design simulation value rather than the measured value. In the case of an ideal voltage source (zero output load), the transmission delay will be better than that of a 50pF load capacitor.

Note 9: Turn off isolation $= 20\log_{10}[V_A/V_{Bn}]$.

Note 10: $T_A=+25^\circ\text{C}$, $f=1\text{MHz}$, excluding the load capacitance introduced by packaging.

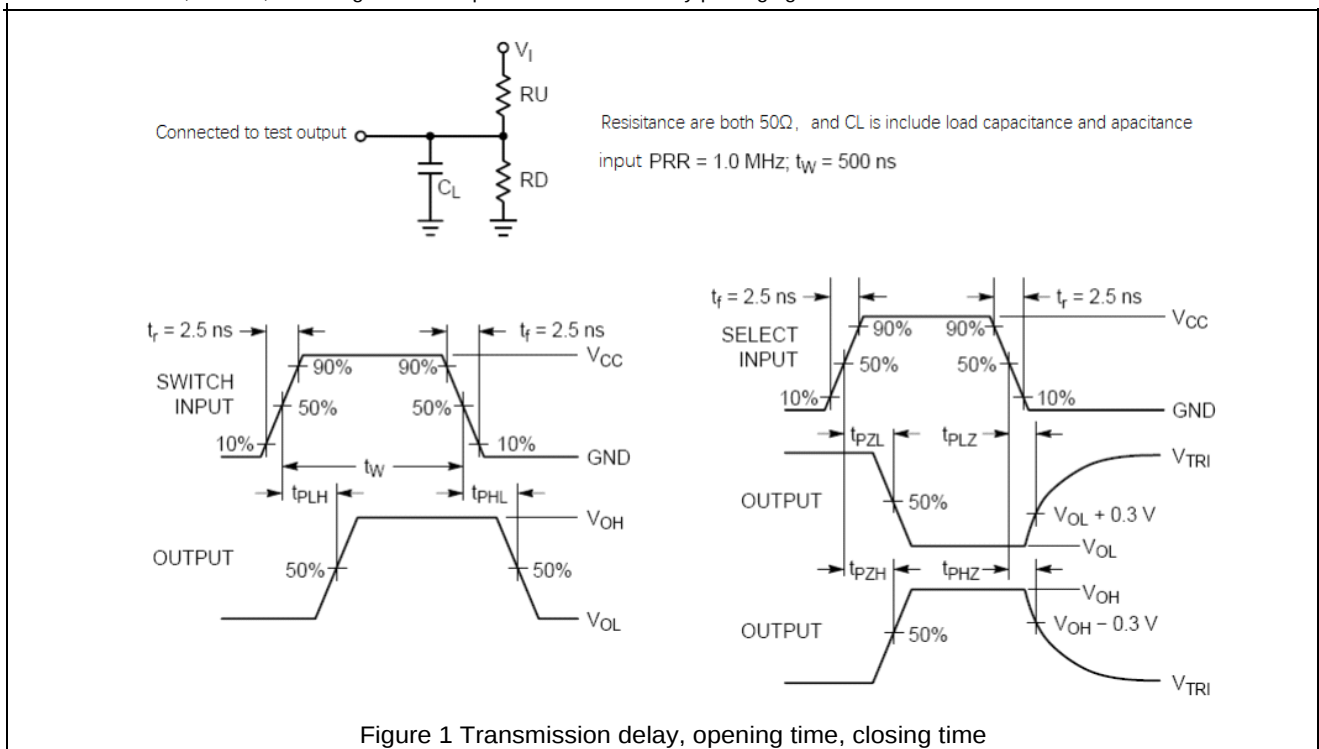




Figure 2: Cut off before opening time

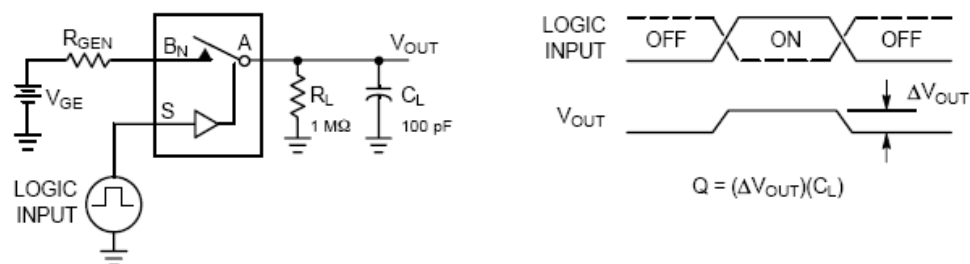


Figure 3 Charge injection test

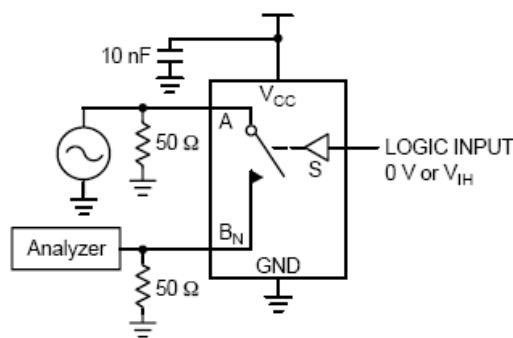


Figure 4 Close quarantine

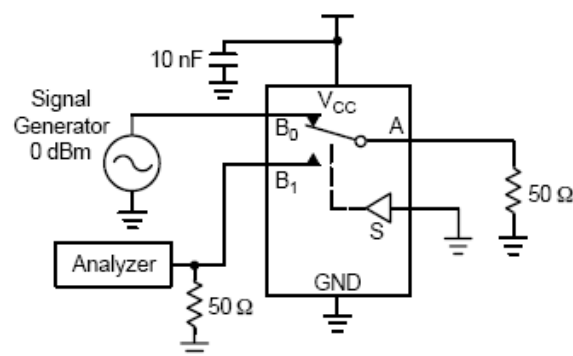


Figure 5 Crosstalk

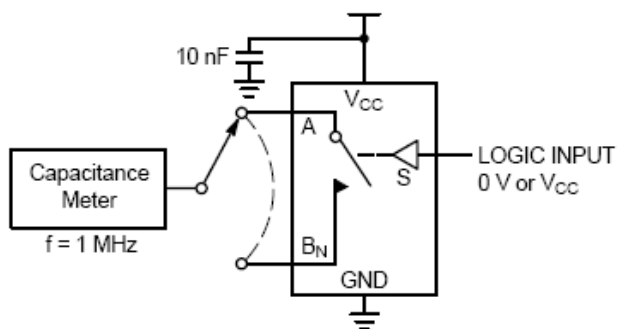


Figure 6 Output capacitance when channel is closed

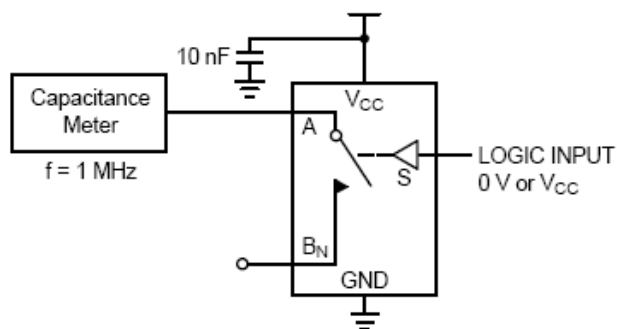


Figure 7 Output capacitance when channel is open

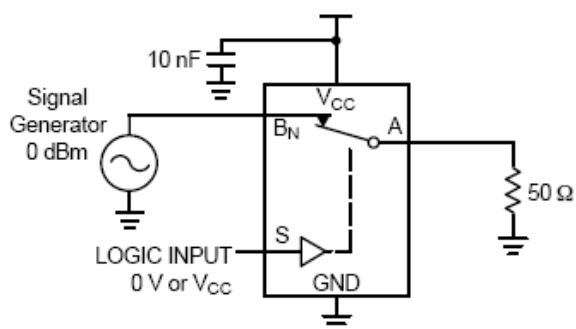
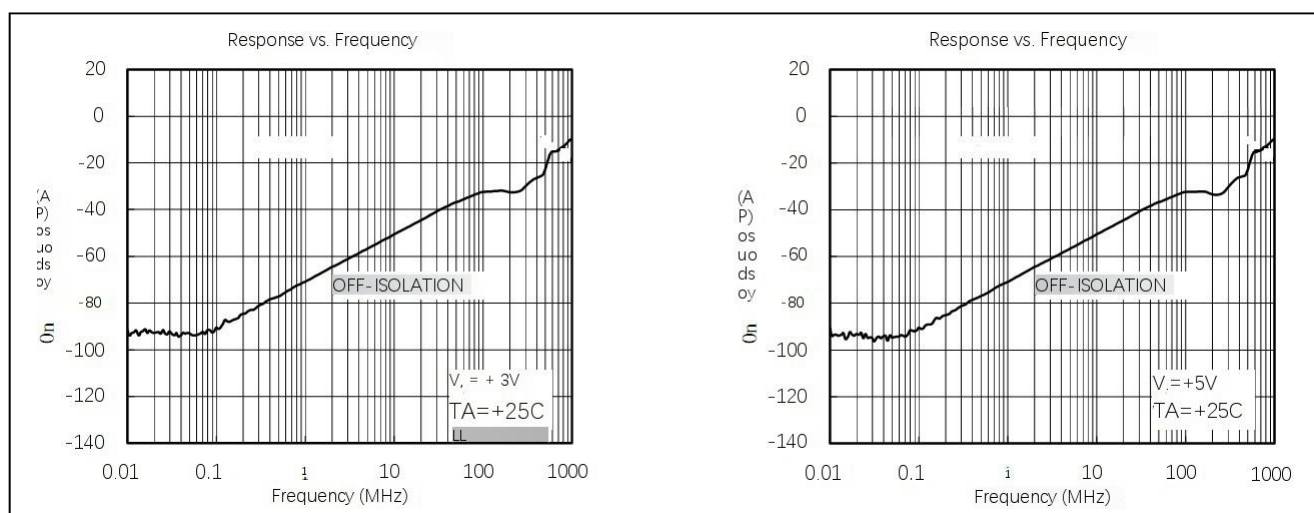
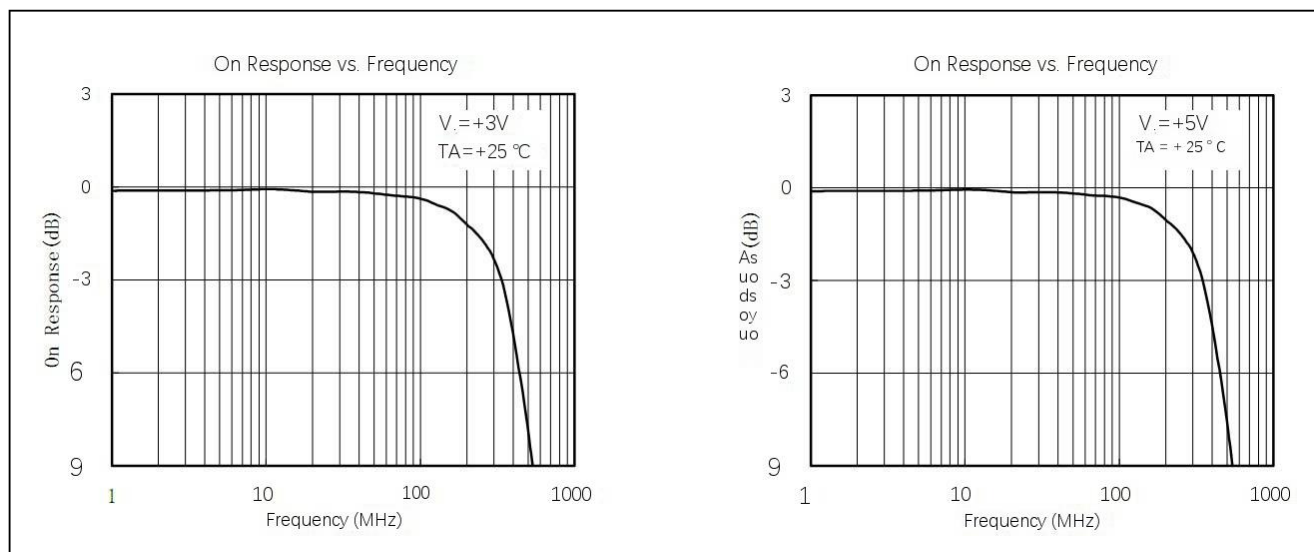
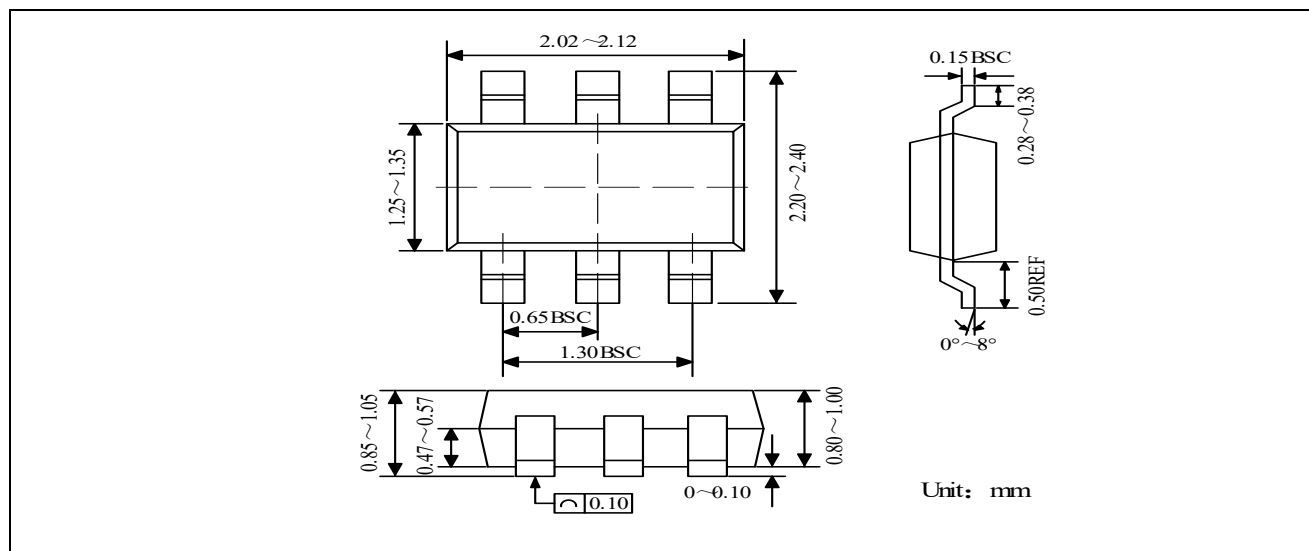


Figure 8 Bandwidth

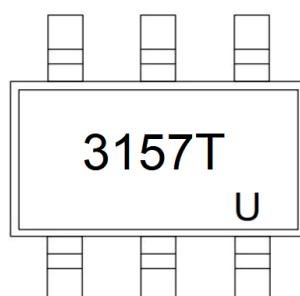


Package size

SC70-6



Marking



Ordering information

Order code	Package	Base qty	Delivery mode
UMW ET3157	SC70-6	3000	Tape and reel